### **Vishay Semiconductors**

## Hyperfast Rectifier, 30 A FRED Pt®



www.vishay.com

PRODUCT SUMMARY						
Package	TO-247AD 3L					
I <sub>F(AV)</sub>	30 A					
V <sub>R</sub>	600 V					
V <sub>F</sub> at I <sub>F</sub>	1.4 V					
t <sub>rr</sub> typ.	26 ns					
T <sub>J</sub> max.	175 °C					
Diode variation	Single die					

### FEATURES

- Low forward voltage drop
- Hyperfast soft recovery time
- 175 °C operating junction temperature
- Designed and qualified according to commercial qualification
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **DESCRIPTION / APPLICATIONS**

Hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC Boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS			
Repetitive peak reverse voltage	V <sub>RRM</sub>		600	V			
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 112 °C	30				
Non-repetitive peak surge current	I <sub>FSM</sub>	$T_C = 25$ °C, $t_p = 8.3$ ms half sine wave; connecting two anode pins	240	A			
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C			

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	600	-	-		
Forward valtage	V	I <sub>F</sub> = 30 A	-	2.0	2.65	V	
Forward voltage V <sub>F</sub>	۷F	I <sub>F</sub> = 30 A, T <sub>J</sub> = 150 °C	-	1.4	1.8		
Povoroa loakago ourrant	1	$V_R = V_R$ rated	-	0.02	30		
Reverse leakage current I <sub>R</sub>		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	300	μA	
Junction capacitance	CT	V <sub>R</sub> = 600 V	-	20	-	pF	
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8.0	-	nH	

Revision: 01-Feb-17

Document Number: 95956

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

1



RoHS

COMPLIANT

HALOGEN

FREE



www.vishay.com

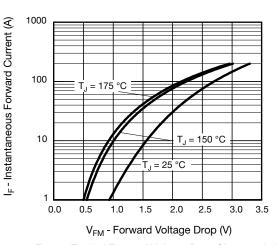
## Vishay Semiconductors

<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS			
		$I_F = 1 \text{ A}, dI_F/dt = 50 \text{ A}/\mu \text{s}, V_R = 30 \text{ V}$		-	26	-			
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	26	-	ns		
		T <sub>J</sub> = 125 °C		-	70	-			
Pook receivery ourrent	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 30 A dI <sub>F</sub> /dt = 200 A/μs V <sub>R</sub> = 200 V	-	3.5	-	А		
Peak recovery current		T <sub>J</sub> = 125 °C		-	7.6	-	A		
	0	T <sub>J</sub> = 25 °C		-	50	-	nC		
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	280	-	nc		

THERMAL - MECHANICA	THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	175	°C		
Thermal resistance, junction to case	R <sub>thJC</sub>		-	0.7	1.1	°C/W		
Thermal resistance, junction to ambient per leg	R <sub>thJA</sub>	Typical socket mount	-	-	70			
Thermal resistance, case to heat sink	R <sub>thCS</sub>	Mounting surface, flat, smooth, and greased	-	0.5	-			
Weight			-	5.5	-	g		
weight			-	0.2	-	oz.		
Mounting torque			1.2 (10)	-	2.4 (20)	kgf · cm (lbf · in)		
Marking device		Case style TO-247AD 3L		APH3	006LH			

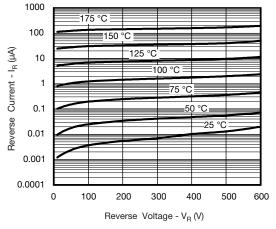
# VS-APH3006LHN3

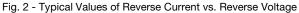
## **Vishay Semiconductors**



www.vishay.com







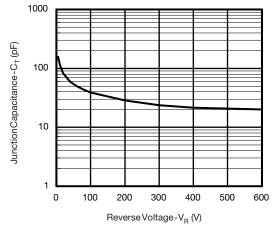
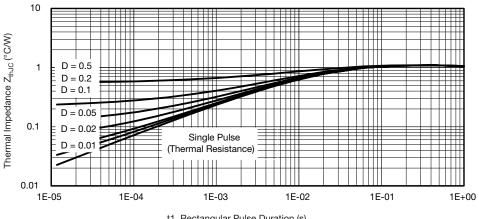
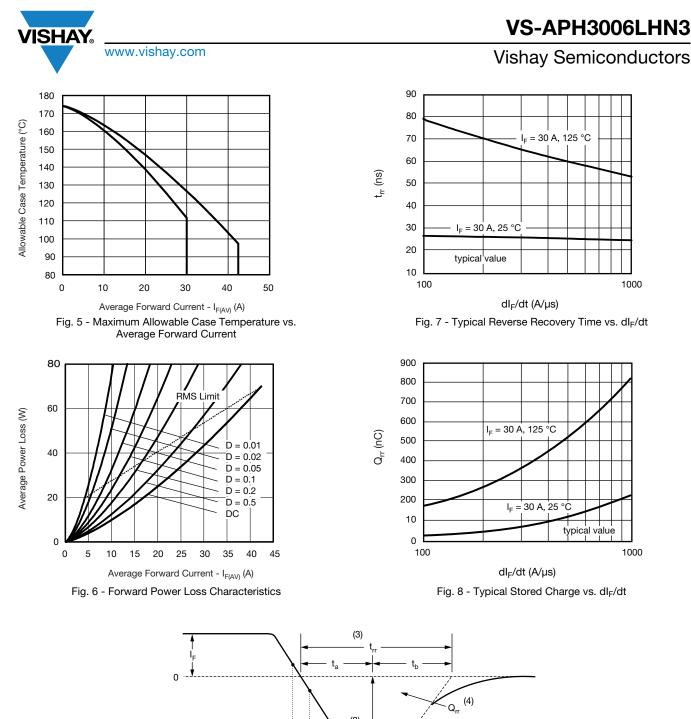


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage



t1, Rectangular Pulse Duration (s)

Fig. 4 - Max. Thermal Impedance Z<sub>thJC</sub> Characteristics



(2) 0.5 I<sub>RRM</sub> I<sub>RRM</sub> dl<sub>(rec)M</sub>/dt (5) 0.75 I<sub>RRM</sub> (1) dl<sub>F</sub>/dt (4)  $Q_{rr}$  - area under curve defined by  $t_{rr}$ (1) dl<sub>F</sub>/dt - rate of change of current and I<sub>RRM</sub> through zero crossing  $Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$ (2) I<sub>RRM</sub> - peak reverse recovery current (3) t<sub>rr</sub> - reverse recovery time measured (5) dI\_{(rec)M}/dt - peak rate of change of current during  $t_{\rm b}$  portion of  $t_{\rm rr}$ from zero crossing point of negative going I<sub>F</sub> to point where a line passing through 0.75 I<sub>RRM</sub> and 0.50 I<sub>RRM</sub>

extrapolated to zero current.

Fig. 9 - Reverse Recovery Waveform and Definitions

Revision: 01-Feb-17	4	Document Number: 95956
For technical questions within your region:	DiodesAmericas@vishay.com, DiodesAsia	@vishay.com, DiodesEurope@vishay.com
THIS DOCUMENT IS SUBJECT TO CHANG ARE SUBJECT TO SPEC	E WITHOUT NOTICE. THE PRODUCTS DE CIFIC DISCLAIMERS, SET FORTH AT <u>www.</u>	

## Vishay Semiconductors



### **ORDERING INFORMATION TABLE**

Device code	VS-	Α	Ρ	Н	30	06	L	Н	N3
	1	2	3	4	5	6	7	8	9
	1 -	Visł	nay Sem	niconduc	ctors pro	oduct			
	2 - Circuit configuration:								
	A = single diode								
	3 -	3 - P = TO-247							
	4 -	H =	hyperfa	ist recov	ery time	Э			
	5 -	Cur	rent cod	le (30 =	30 A)				
	6 -	Volt	age coo	le (06 =	600 V)				
	7 - L = long lead								
	8 -	H =	AEC-Q	101 qua	lified				
	9 -			ntal digit en-free,		ompliar	nt, and t	otally le	ead (Pb

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-APH3006LHN3	25	500	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS				
Dimensions	TO-247AD 3L	www.vishay.com/doc?95626		
Part marking information	TO-247AD 3L	www.vishay.com/doc?95007		



**Vishay Semiconductors** 

TO-247AD 3L

#### **DIMENSIONS** in millimeters and inches



View B

SYMBOL	MILLIN	IETERS	INCHES		NOTES
STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
с	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

(2, 52, 51) (4) Section C - C, D - D, E - E

SYMBOL	MILLIN	IETERS	INC	INCHES	
STNIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	5 BSC	
ØК	0.2	254	0.0	010	
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØР	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217	' BSC	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

- <sup>(3)</sup> Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- <sup>(5)</sup> Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- <sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

 Revision: 06-Mar-2020
 1
 Document Number: 95626

 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com
 DiodesEurope@vishay.com

 THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



Vishay

## Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Vishay products are not designed for use in life-saving or life-sustaining applications or any application in which the failure of the Vishay product could result in personal injury or death unless specifically qualified in writing by Vishay. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

© 2025 VISHAY INTERTECHNOLOGY, INC. ALL RIGHTS RESERVED

Revision: 01-Jan-2025

1